



The Effects of Humidity and Pressure on the Low Field Resistivity of Zinc Oxide Based Varistor Granules

Terry Garino

**Sandia National Laboratories
Albuquerque, NM 87185-1411, USA**

**Presented at the Materials Science and Technology 2014
October 15, 2014
Pittsburgh, PA**

Sandia is a multiprogram laboratory operated by Sandia Corporation, a Lockheed Martin Company, for the United States Department of Energy's National Nuclear Security Administration under Contract DE-AC04-94AL85000.



Outline

1. Introduction

- i. Background on ZnO varistors**
- ii. Motivation for studying granules**

2. Experimental Procedure

- i. Fabrication and characterization of granules**
- ii. Electrical measurements**

3. Results and Discussion

- i. i-V characterization**
- ii. Effect of humidity**
- iii. Effect of compressive stress**

4. Conclusions

Electrical Behavior of Varistors: Non-linear i-V Characteristic.

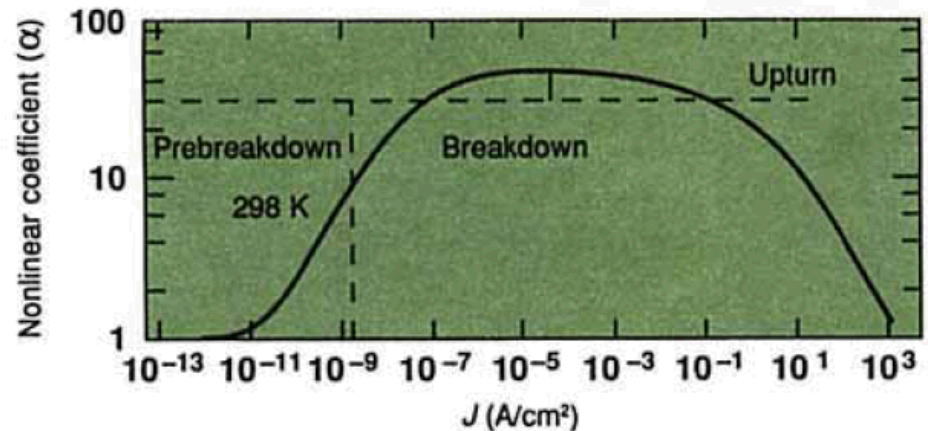
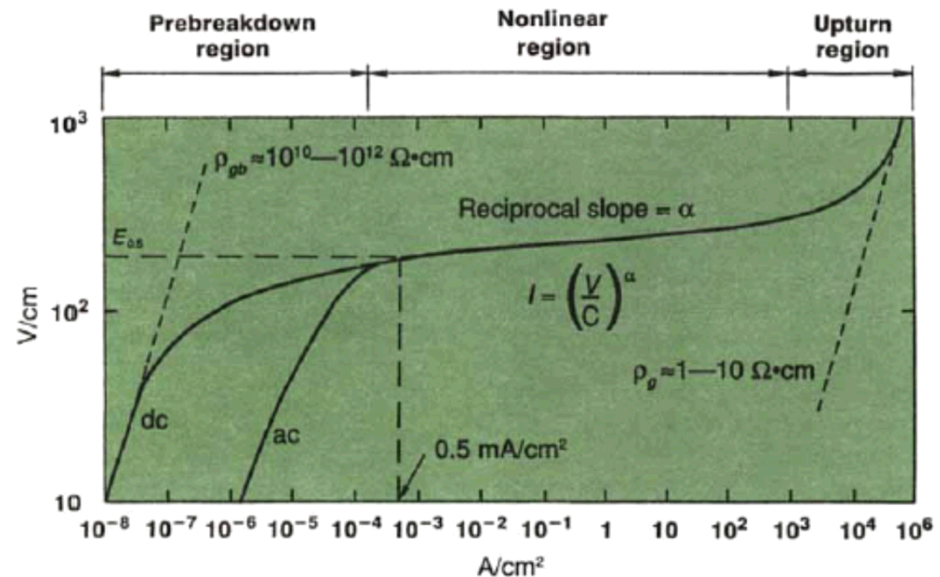
Varistors are good insulators at low E but switch to being conducting at the switching field.

They are ohmic at very low fields.

Non-linearity increases with applied field to a maximum and then decreases.

In the breakdown region, the non-linearity, α , coefficient can be >30 .

$$I = \left(\frac{V}{C} \right)^\alpha = KV^\alpha$$



T. Gupta, "Application of Zinc Oxide Varistors," *J. Am. Ceram. Soc.*, **73** (7) 1817-1840 (1990).

MS&T 2014, Pittsburgh, PA, October 15, 2014

Origin of Varistor Effect: Voltage barriers due to segregation at ZnO grain boundaries.

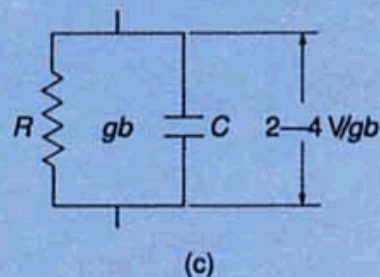
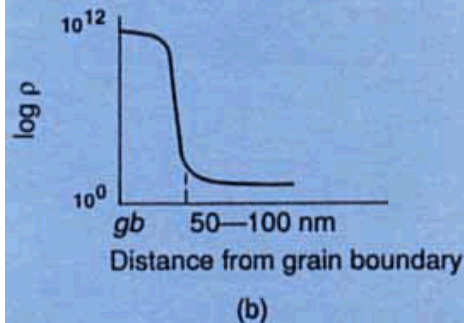
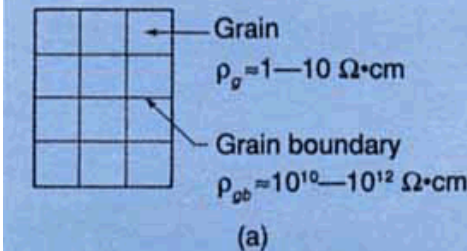
Segregation at ZnO grain boundaries results in a ~3V barrier that is ~100 nm thick.

ZnO grains are semiconducting.

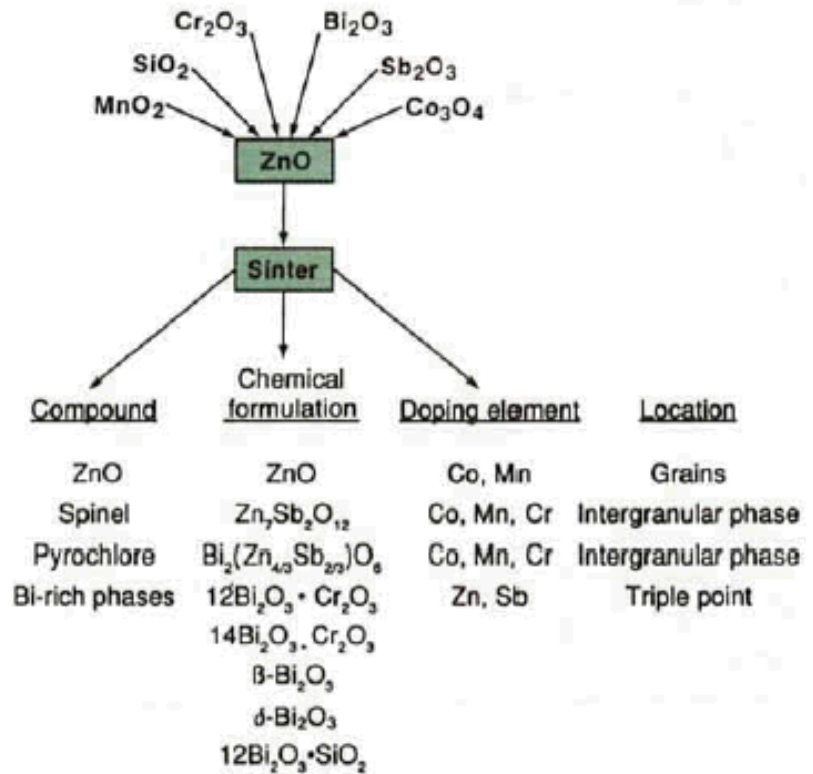
Bi or other elements at GB create barrier.

Tunneling occurs at low E.

Once applied V is enough to surpass all GB barriers, switching to high conductivity occurs.



Commercial varistors can have complex compositions and microstructures.





Motivation of Present Study

- **Goal of this study: characterize varistor granule environmental performance.**
 - **Effect of humidity on electrical properties**
 - **Effect of pressure on electrical properties**
- **Varistor material: BaO- and Co_3O_4 -doped ZnO.**
- **Granules were made by pressing calcined powder into compacts that were crushed or using a droplet technique and then sintered.**
- **Resulting granules were typically 150 to 300 μm in size.**



Granule Fabrication and Characterization

- The typical granule composition was 98.2 at% ZnO, 1.0 at% BaO and 0.8 at% Co_3O_4 .
- Some samples were made by crushing a green pellet others by a droplet technique.
- Sintering was done in air at 1200°C for 3 hr followed by an anneal at 1150°C for 3 hr.
- Granules were characterized used SEM, EDS and XRF.
- Bulk samples as well as granules made by crushing bulk sintered samples were characterized electrically.

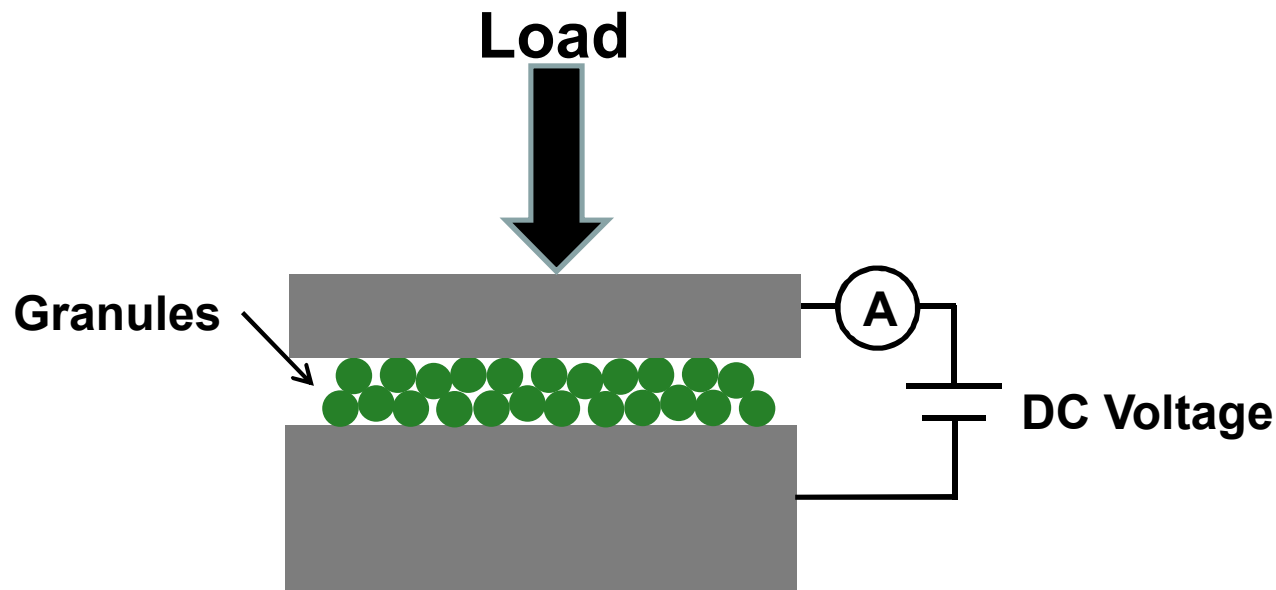
Electrical Characterization

A Keithley 237 High Voltage Source Measure Unit was used to measure the current flowing through a thin granule layer as a function of applied voltage.

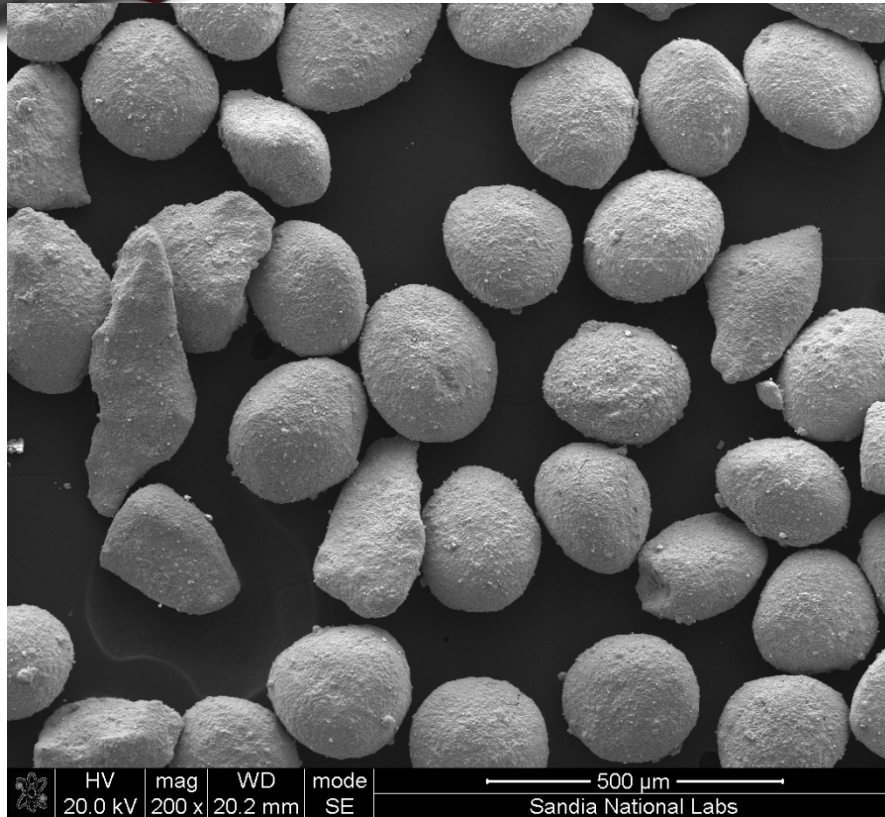
The layer was ~1 mm thick and metal (steel) plates were used as the electrodes.

Some measurements were made in a controlled humidity chamber.

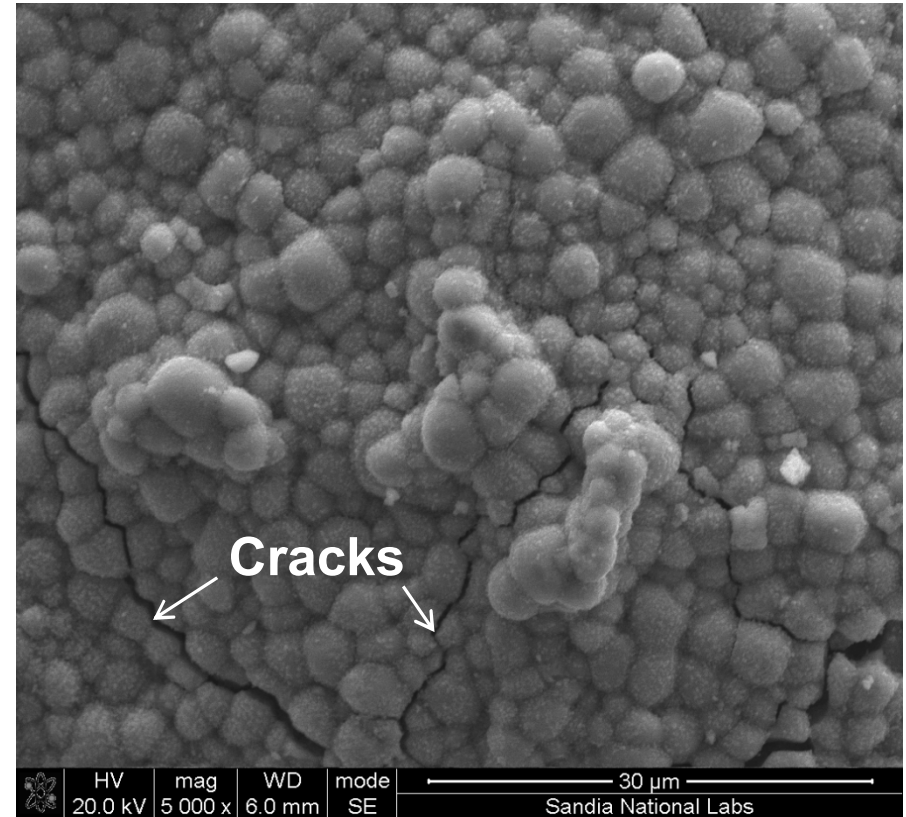
Loads were applied to the top plate electrode ranging from 0.01 to 30 bar.



Typical Rounded Granules



150 to 300 μm Granules

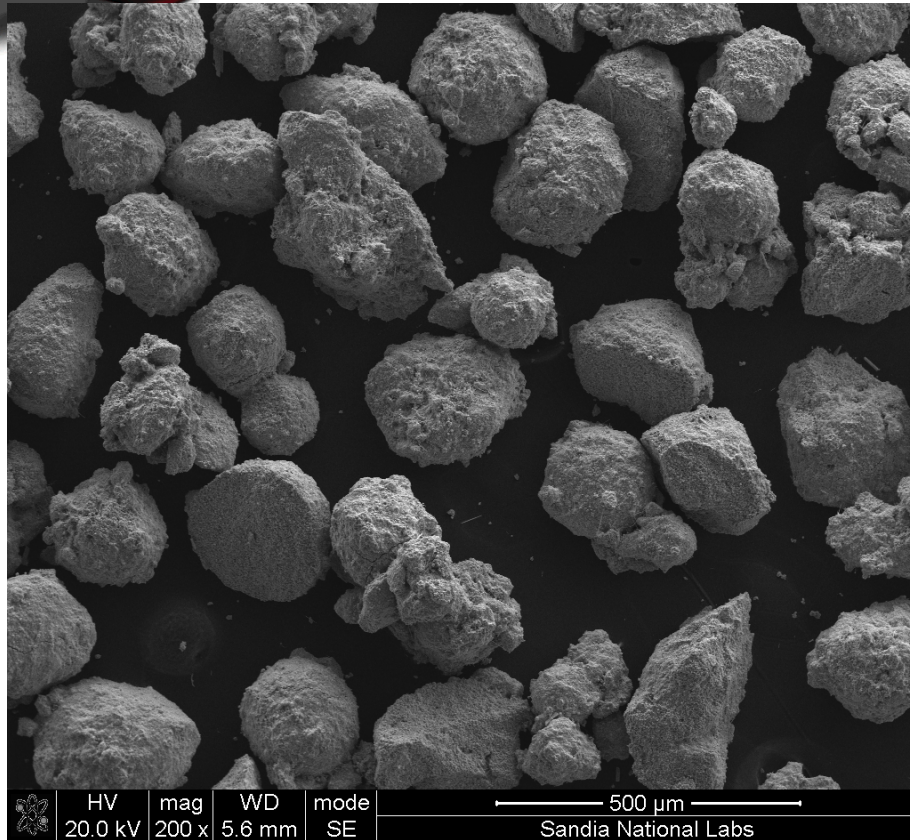


2 to 3 μm GS

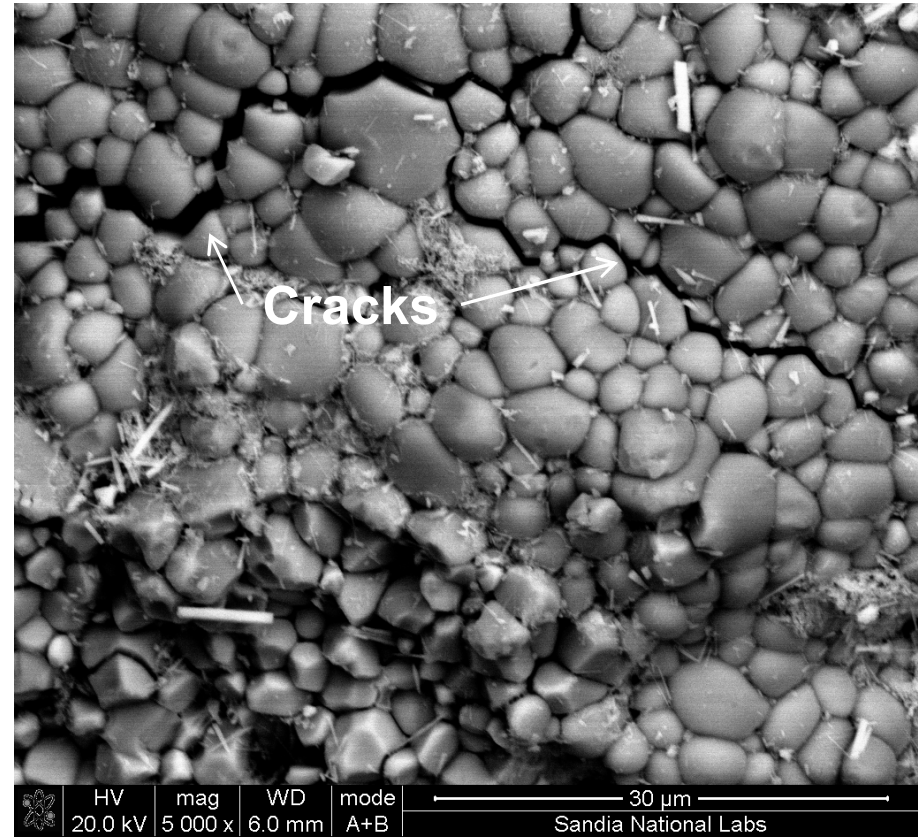
XRF Results

Element	AN	Net	norm. C. [wt.%]	Atom C. [at.%]	Error (1 Sigma) [wt.%]
Zinc	30	17129960	97.17	98.22	2.08
Cobalt	27	282023	0.66	0.74	0.00
Barium	56	208579	2.17	1.04	0.00
		Total	100.00	100.00	

Typical Crushed Granules



150 to 400 μm Granules



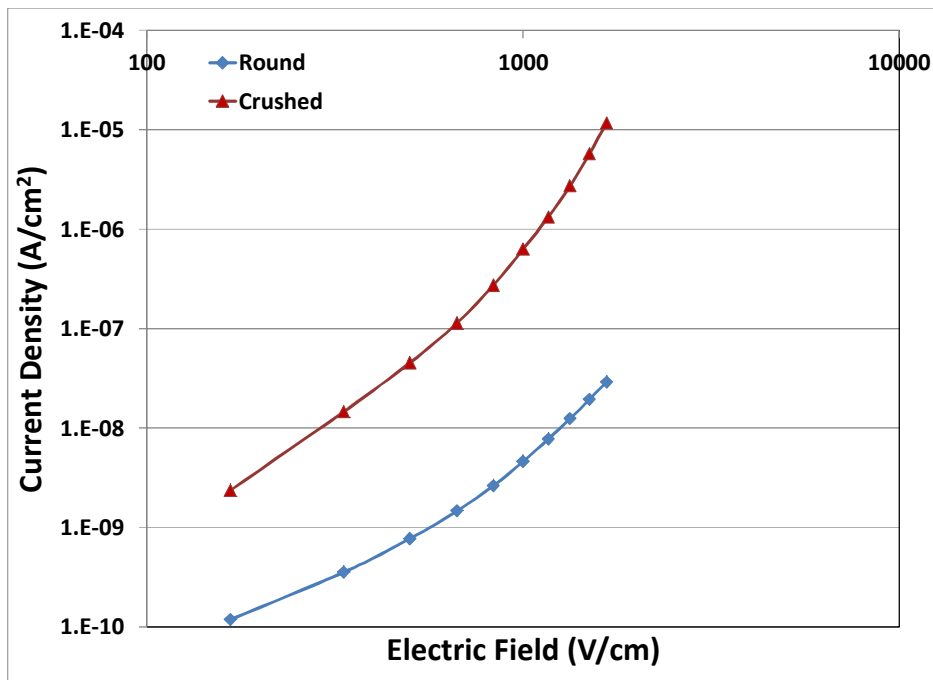
3 to 10 μm GS

XRF Results

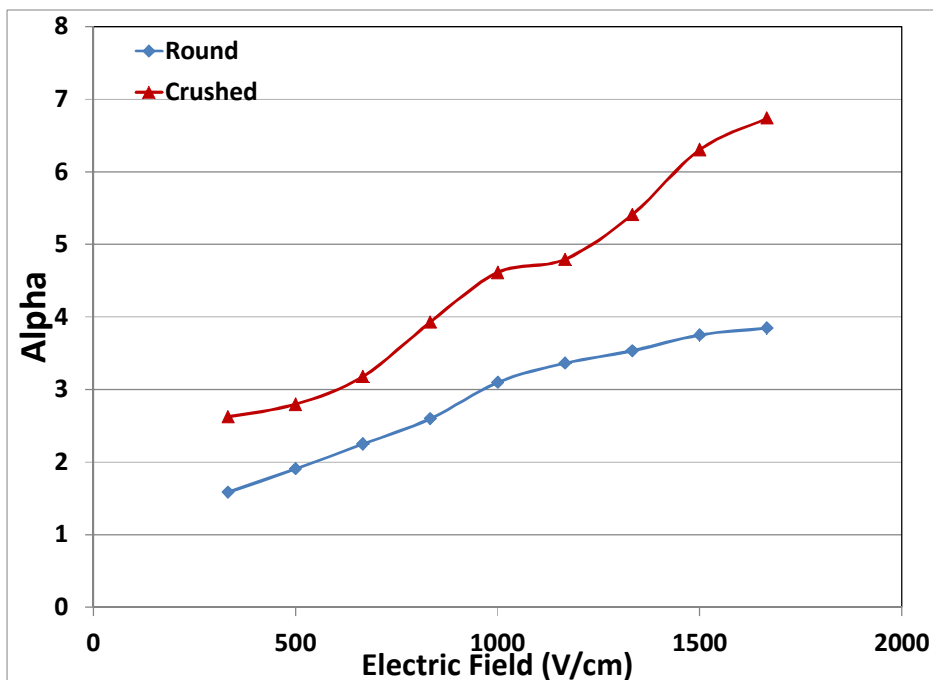
Element	AN	Net	norm. C. [wt.%]	Atom C. [at.%]	Error (1 Sigma) [wt.%]
Zinc	30	17616282	97.01	98.10	2.21
Cobalt	27	316550	0.71	0.80	0.00
Barium	56	227029	2.28	1.10	0.00
		Total	100.00	100.00	

i-V characteristics for varistor granules are similar to bulk behavior.

Non-linear i-V behavior

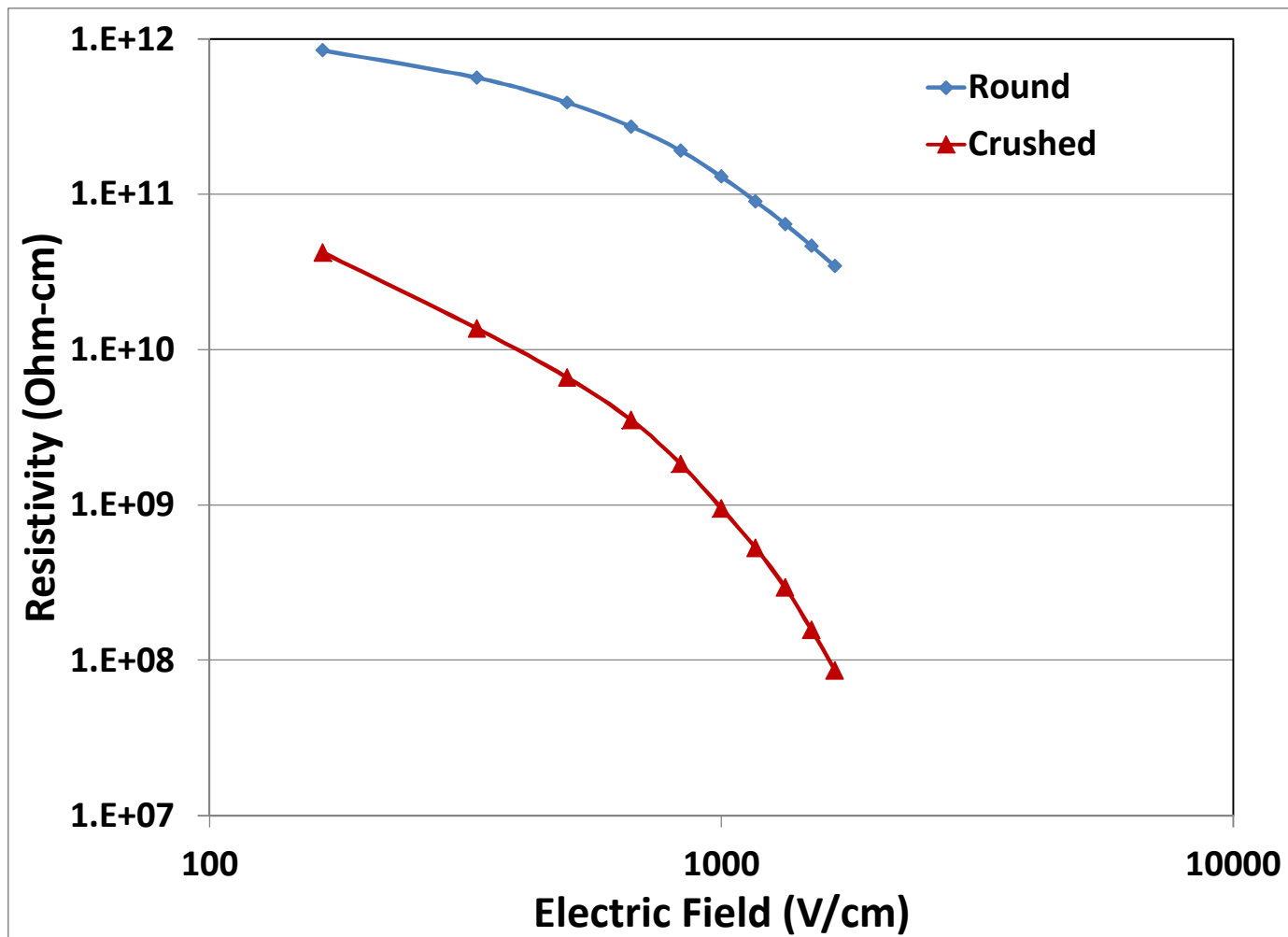


α increases with E



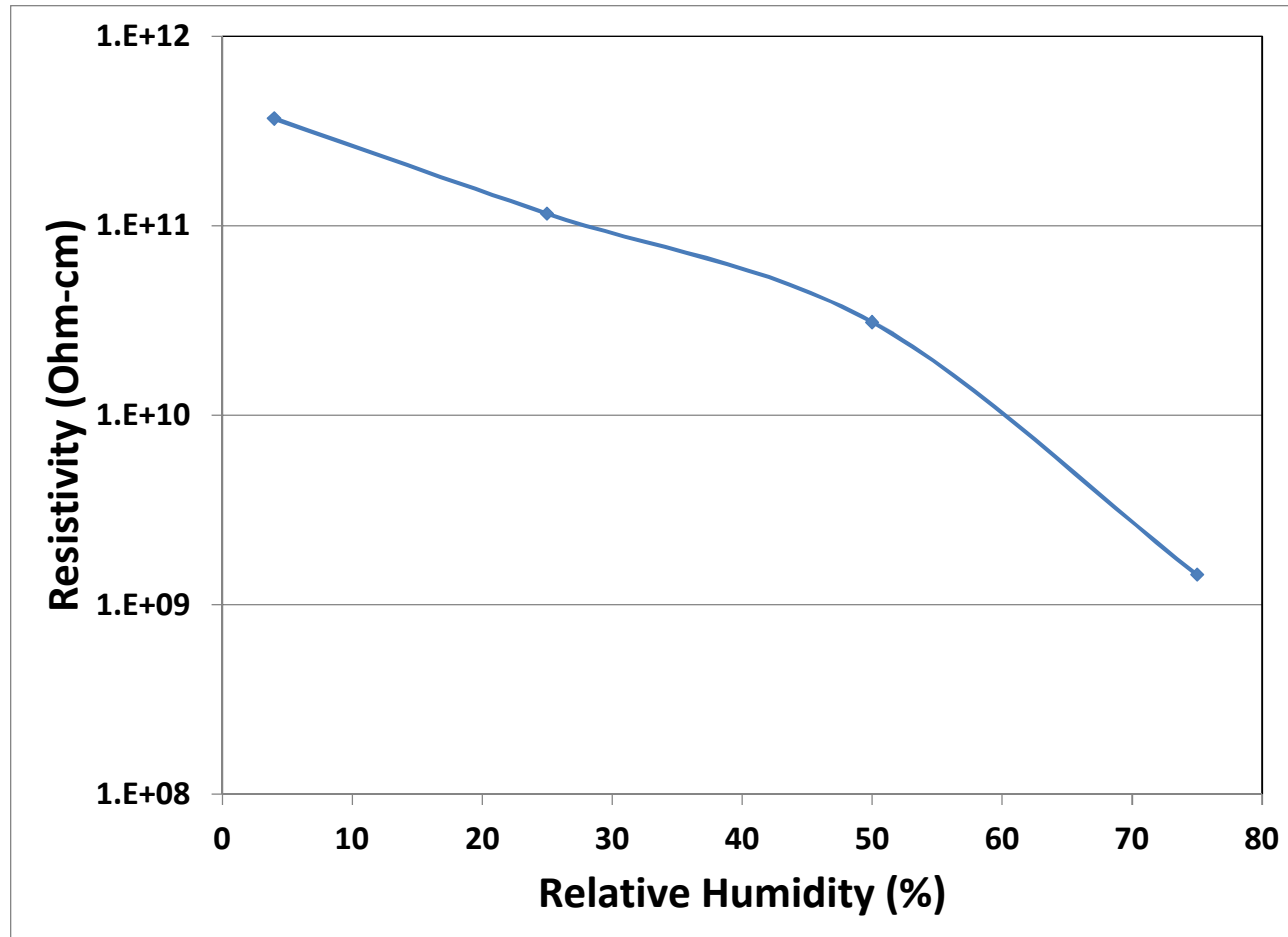


Granule low-field resistivity was in the expected range





Resistivity of varistor granules decreased by several order of magnitude with increasing RH.



Change in ρ was rapid and reversible implying it was due to **adsorption of water vapor.**

Previous work* on thin-film ZnO varistors showed similar results.

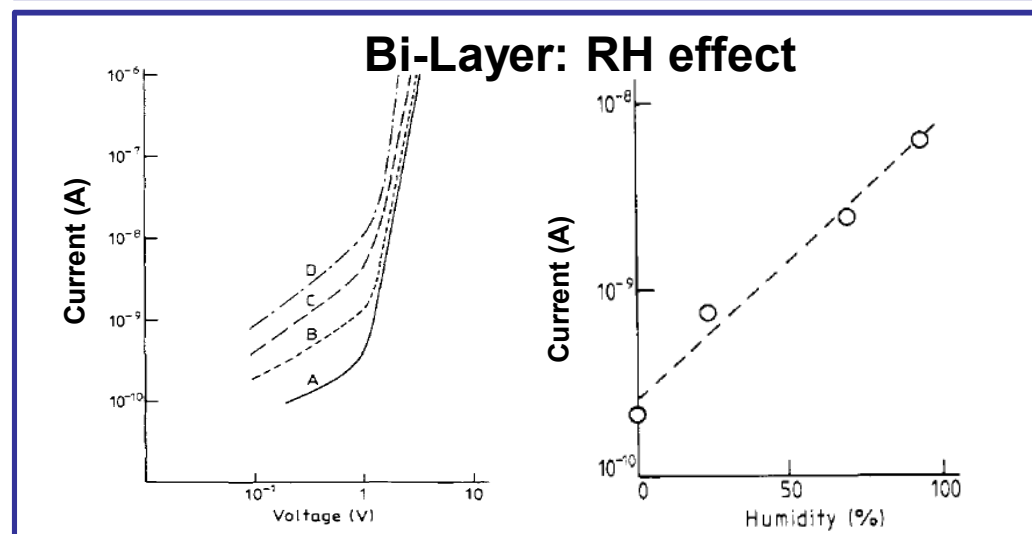
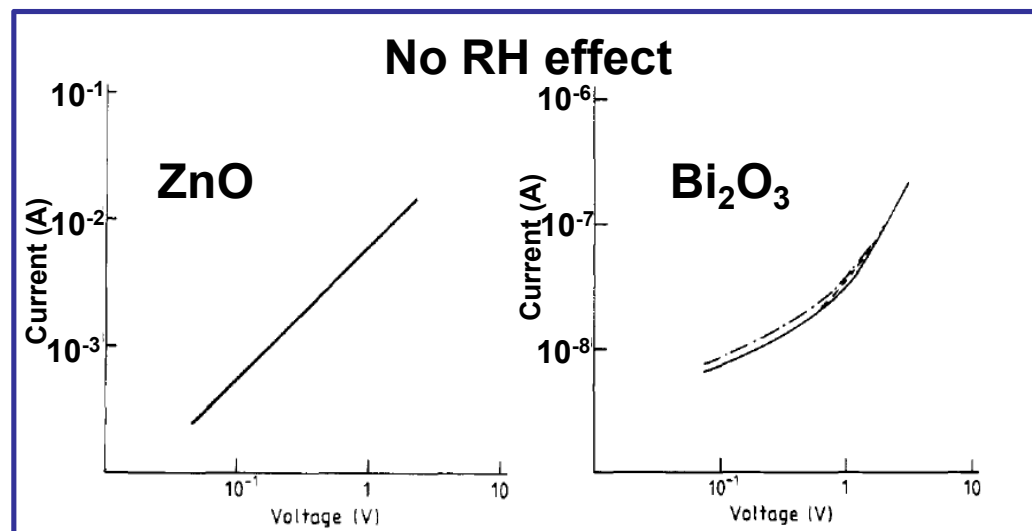
They measured I-V curves at 0%, 22%, 69% and 93% RH on individual ZnO and Bi₂O₃ layers and on a bi-layer.

No RH effect for individual layers.

Large RH effect for bi-layer.

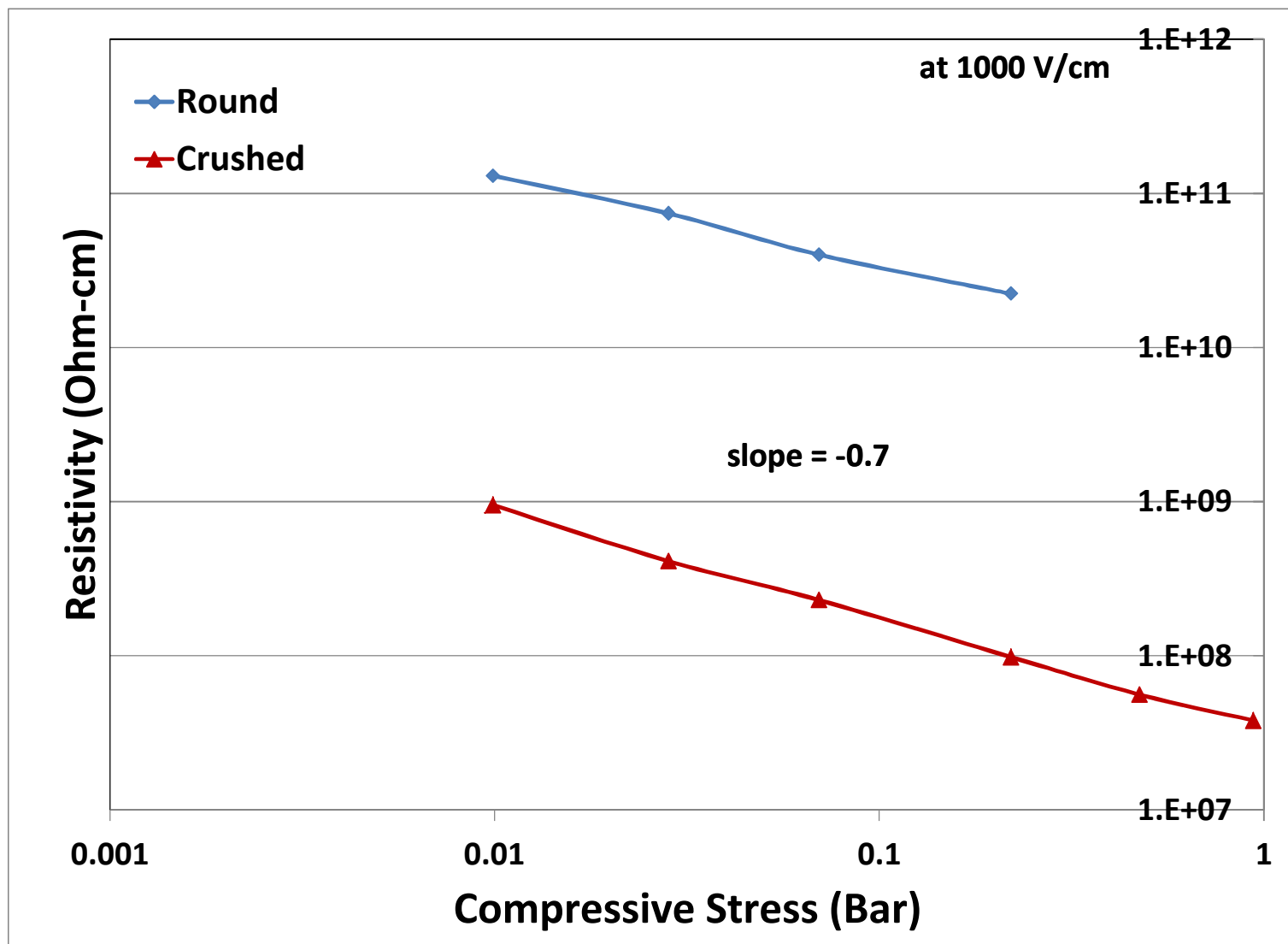
No effects found for other vapors including ethanol.

Explanation: Adsorption of water lowers the voltage barrier at the boundary in a reversible manner.



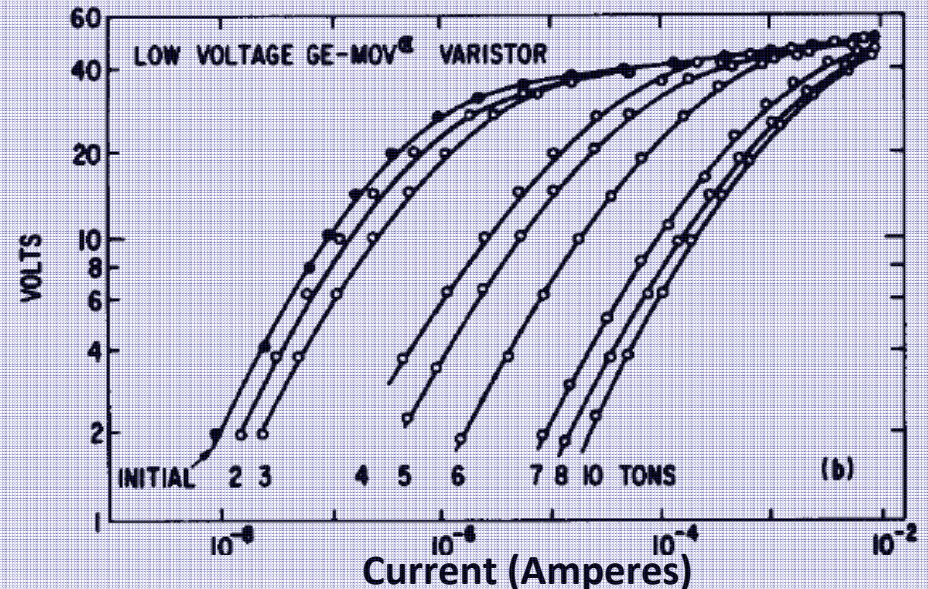
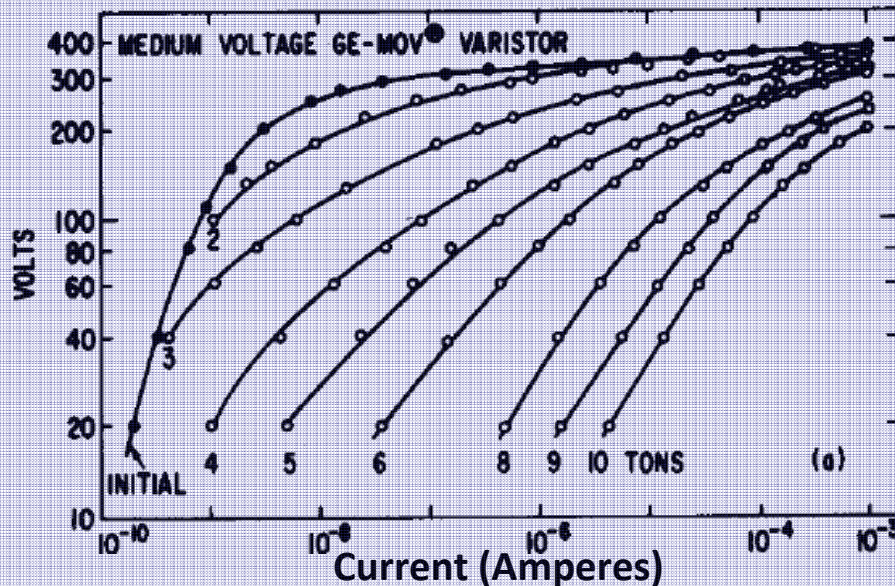
*Y. Suzuki, A. Ohki, T. Mizutani and M. Ieda, "Humidity Dependence of Electrical Conduction in ZnO-Bi₂O₃ Thin-Film Composites," *J. Phys. D: Appl. Phys.* **20** 518-521 (1987).

The granule resistivity decreased strongly with compressive stress at low stress levels.



Work in the 1970's showed that compressive stress decreases low-field resistivity of bulk ZnO varistors.

i-V curves for two types of commercial varistors.



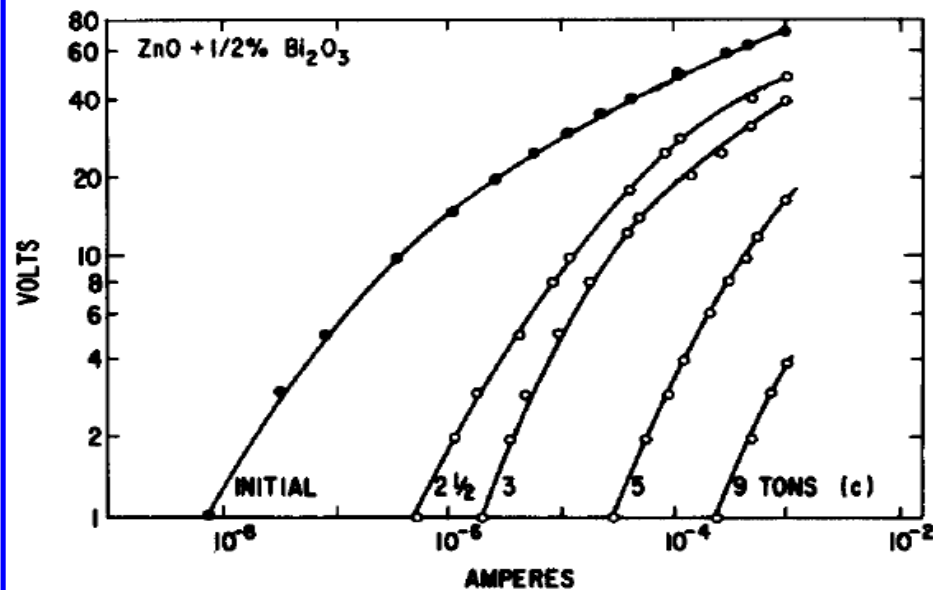
Note: 1 ton of load equaled 550 Bar of stress.

- This effect was due to the lowering of the GB barrier voltage with stress.
- Changes occurred at much higher stress levels and with granules.

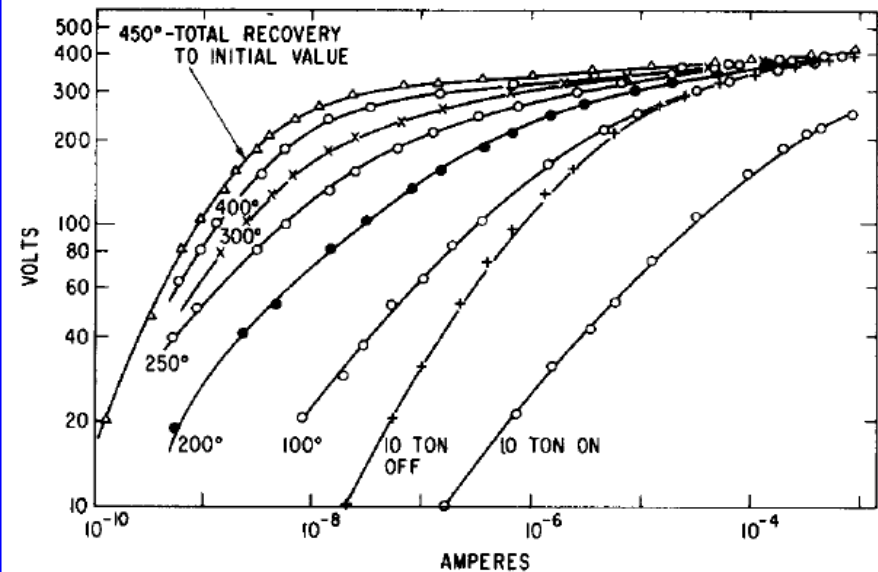
J. Wong and F.P. Bundy, "Pressure Effects on Metal Oxide Varistors," *Appl. Phys. Lett.* **29** 49-50 (1976)

High stress was required for a simple composition and stress caused an irreversible change in ρ .

Simple composition: Effect occurs at somewhat lower stress.

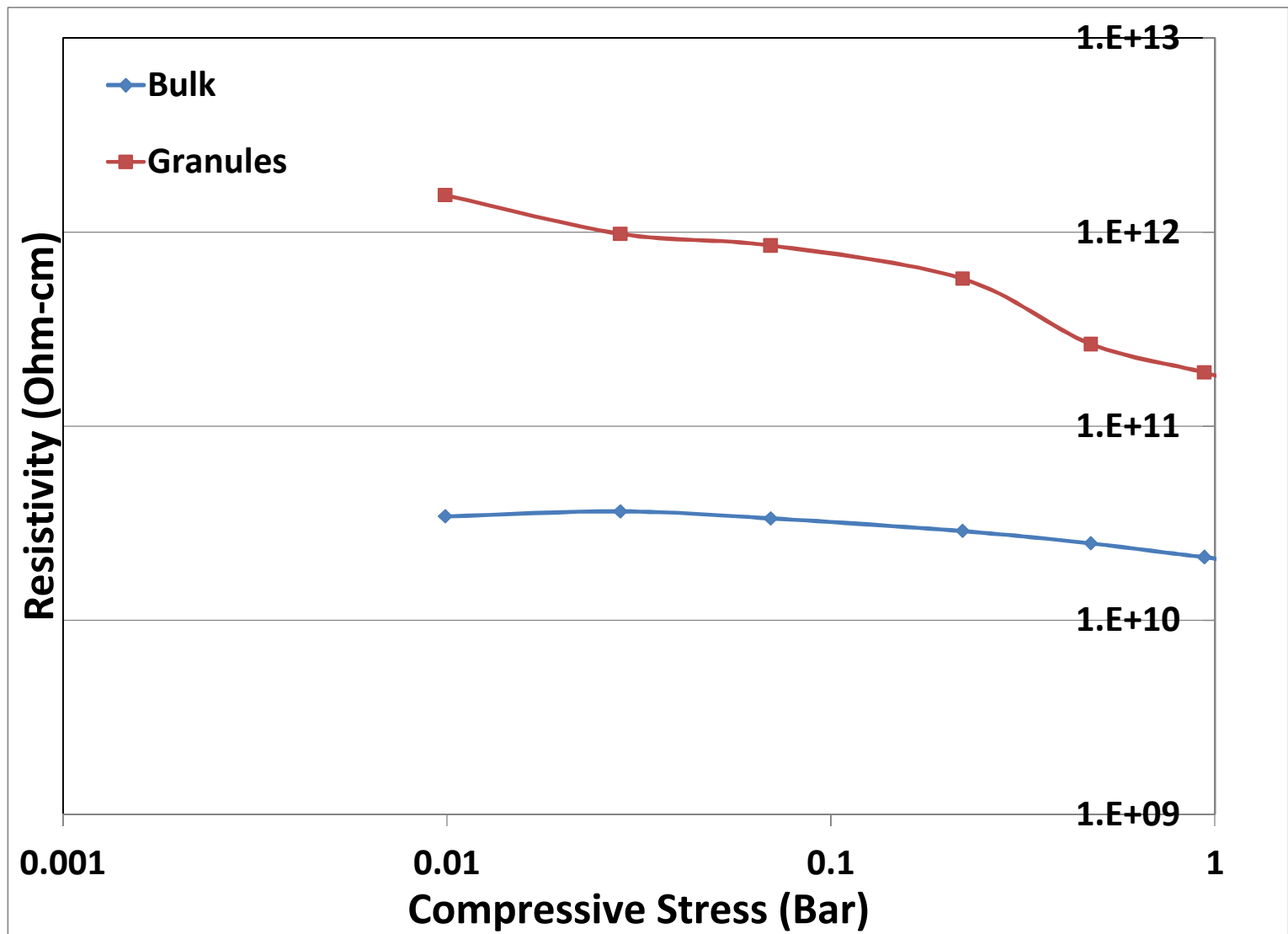


Annealing at 450C was required for total recovery.



These characteristics are not consistent with the results on varistor granules.

Crushing a bulk varistor pellet increased its pressure sensitivity.





Conclusions

- 1. Varistor granules have low field i-V characteristics similar to bulk varistors but with increased sensitivity to humidity and compressive stress.**
- 2. Their resistivity can decrease by over 2 orders of magnitude as the RH increases from low to high.**
- 3. This effect is caused by the adsorption of water vapor, which lowers the grain boundary barrier near the surface.**
- 4. The measured resistivity of varistor granules is pressure sensitive at very low pressures.**
- 5. The pressure sensitivity is not due to the same mechanism that decreases the barrier height of bulk varistors at much higher pressure.**
- 6. More research is needed to determine the mechanism but it appears to be caused by pressure sensitivity at the contact points that is increased in varistor materials.**